Low frequency transistor (-20V, -5A) 2SB1386 / 2SB1412 / 2SB1326

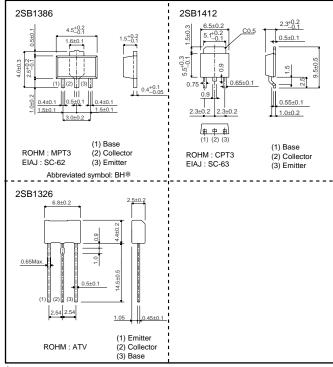
●Features

- 1) Low VCE(sat). VCE(sat) = -0.35V (Typ.)(Ic/IB = -4A/-0.1A)
- 2) Excellent DC current gain characteristics.
- Complements the 2SD2098 / 2SD2118 / 2SD2097.

●Structure

Epitaxial planar type PNP silicon transistor

●External dimensions (Unit : mm)



* Denotes hre

● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	-30	V	
Collector-emitter voltage		Vceo	-20	V	
Emitter-base voltage		VEBO	-6	V	
Collector current			-5	A(DC)	
		lc lc	-10	A(Pulse) *1	
Collector power dissipation	2SB1386		0.5	W	
			2	W *2	
	2SB1412	Pc	1	W	
			10	W(Tc=25°C)	
	2SB1326		1	W *3	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to 150	°C	

●Electrical characteristics (Ta=25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage		ВУсво	-30	-	-	V	Ic= -50μA	
Collector-emitter breakdown voltage		BVceo	-20	-	-	V	Ic=-1mA	
Emitter-base breakdown voltage		ВУево	-6	-	-	V	I _E = -50μA	
Collector cutoff current		Ісво	-	-	-0.5	μΑ	Vcb= -20V	
Emitter cutoff current		ІЕВО	-	-	-0.5	μΑ	V _{EB} = -5V	
Collector-emitter saturation voltage		VCE(sat)	-	0.35	-1.0	V	Ic/I _B = -4A/ -0.1A *	
DC current	2SB1386,2SB1412	hfe	82	-	390	-	Vce= -2V, Ic= -0.5A	
transfer ratio	2SB1326		120	-	390	-	* **	
Transition frequency		f⊤	-	120	-	MHz	Vc=-6V, I=50mA, f=100MHz	
Output capacitance		Cob	-	60	-	pF	Vcb= -20V, Ie=0A, f=1MHz	

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●Packaging specifications and hFE

		Package	Taping		
		Code	T100	TL	TV2
Туре	hfe	Basic ordering unit (pieces)	1000	2500	2500
2SB1386	PQR		0	-	_
2SB1412	PQR		_	0	_
2SB1326	QR		_	-	0

hre values are classified as follows:

Item	Р	Q	R	
hfe	82 to 180	120 to 270	180 to 390	

Rev.A

2/4

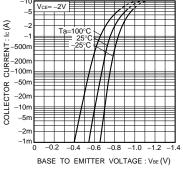
^{*1} Single pulse, Pw=10ms

*2 When mounted on a 40×40×0.7 mm ceramic board.

*3 Printed circuit board glass epoxy board 1.6 mm thick with copper plating 100mm² or larger.

^{*} Measured using pulse current.

Electrical characteristic curves



-3 -50mA -30mA -25°C -30mA -40mA -25mA -20mA -15mA -15mA -10mA -10mA -25mD -10mA -15mA -10mA -10

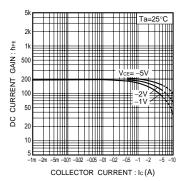
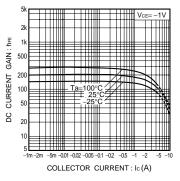
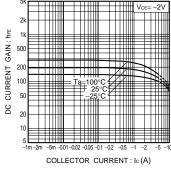


Fig.1 Grounded emitter propagation characteristics

Fig.2 Grounded emitter output characteristics

Fig.3 DC current gain vs. collector current (I)





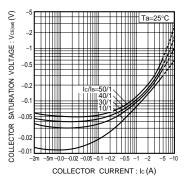
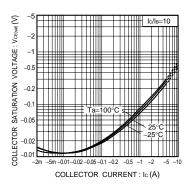
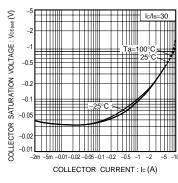


Fig.4 DC current gain vs. collector current (II)

Fig.5 DC current gain vs. collector current (III)

Fig.6 Collector-emitter saturation voltage vs. collector current (I)





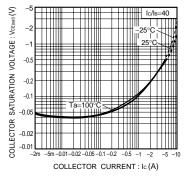


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

Fig.8 Collector-emitter saturation voltage vs. collector current (III)

Fig.9 Collector-emitter saturation voltage vs. collector current (IV)

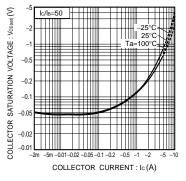


Fig.10 Collector-emitter saturation voltage vs. collector current (V)

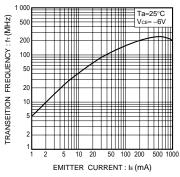


Fig.11 Gain bandwidth product vs. emitter current

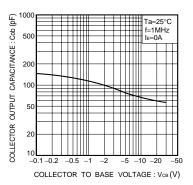


Fig.12 Collector output capacitance vs. collector-base voltage

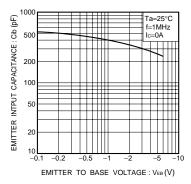


Fig.13 Emitter input capacitance vs. emitter-base voltage

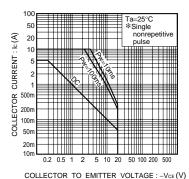


Fig.14 Safe operation area (2SB1412)

Rev.A

4/4

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Appendix1-Rev1.1